Philips Components–Signetics

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Status	Product Specification
Memory Products	

82S126
82S129
1K-bit TTL bipolar PROM

DESCRIPTION

The 82S126 and 82S129 are field programmable, which means that custom patterns are immediately available by following the Signetics Generic I fusing procedure. The 82S126 and 82S129 devices are supplied with all outputs at logical Low. Outputs are programmed to a logic High level at any specified address by fusing the Ni-Cr link matrix.

These devices include on-chip decoding and 2 Chip Enable inputs for ease of memory expansion. They feature either Open Collector or 3-State outputs for optimization of word expansion in bused organizations.

Ordering information can be found on the following page.

The 82S126 and 82S129 devices are also processed to military requirements for operation over the military temperature range. For specifications and ordering information, consult the Signetics Military Data Handbook.

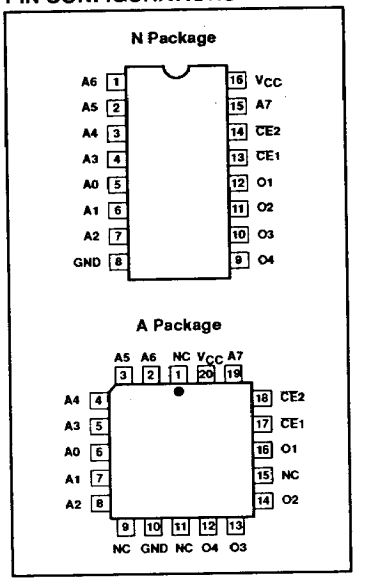
FEATURES

- Address access time: 50ns max
- Power dissipation: 0.5mW/bit typ
- Input loading: –100μA max
- On-chip address decoding
- Two Chip Enable inputs
- Output options:
  - N82S126: Open Collector
  - N82S129: 3-State
- No separate fusing pins
- Unprogrammed outputs are Low level
- Fully TTL compatible

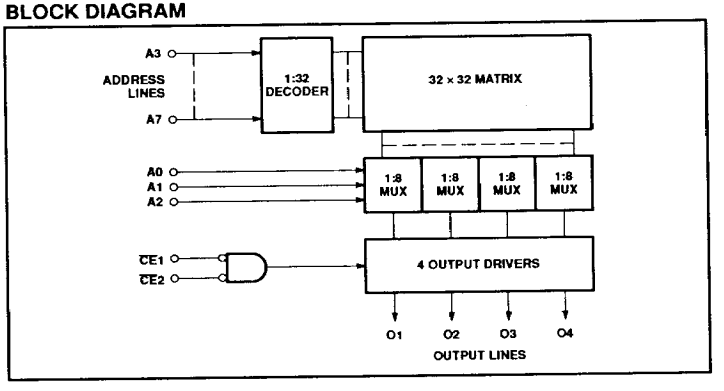
APPLICATIONS

- Prototyping/volume production
- Sequential controllers
- Format conversion
- Hardwired algorithms
- Random logic
- Code conversion

PIN CONFIGURATIONS



BLOCK DIAGRAM



1K-bit TTL bipolar PROM (256 × 4) — 82S126 / 82S129

ORDERING INFORMATION

DESCRIPTION	ORDER CODE
16-Pin Plastic Dual-In-Line 300mil-wide	N82S126 N, N82S129 N
20-Pin Plastic Leaded Chip Carrier 350mil-square	N82S126 A, N82S129 A

ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	RATING	UNIT
V_{CC}	Supply voltage	+7.0	V_{DC}
V_{IN}	Input voltage	+5.5	V_{DC}
V_{OH}	Output voltage High (82S126)	+5.5	V_{DC}
V_O	Output voltage Off-State (82S129)	+5.5	V_{DC}
T_{amb}	Operating temperature range	0 to +75	°C
T_{stg}	Storage temperature range	-65 to +150	°C

DC ELECTRICAL CHARACTERISTICS

$0°C \leq T_{amb} \leq +75°C$, $4.75V \leq V_{CC} \leq 5.25V$

SYMBOL	PARAMETER	TEST CONDITIONS[1,2]	LIMITS			UNIT
			MIN	TYP[3]	MAX	
Input voltage						
V_{IL}	Low				0.8	V
V_{IH}	High		2.0			V
V_{IC}	Clamp	I_{IN} = -12mA			-1.2	V
Output voltage						
		$\overline{CE}1,2$ = Low				
V_{OL}	Low	I_{OUT} = 16mA			0.45	V
V_{OH}	High (82S129)	I_{OUT} = -2.0mA	2.4			V
Input current						
I_{IL}	Low	V_{IN} = 0.45V			-100	µA
I_{IH}	High	V_{IN} = 5.5V			40	µA
Output current						
I_{OLK}	Leakage (82S126)	$\overline{CE}1$ or $\overline{CE}2$ = High, V_{OUT} = 5.5V			40	µA
I_{OZ}	Hi-Z state (82S129)	$\overline{CE}1$ or $\overline{CE}2$ = High, V_{OUT} = 5.5V			40	µA
		$\overline{CE}1$ or $\overline{CE}2$ = High, V_{OUT} = 0.5V			-40	µA
I_{OS}	Short circuit (82S129)[4]	$\overline{CE}1,2$ = Low, V_{OUT} = 0V, High stored	-15		-70	mA
Supply current[5]						
I_{CC}		V_{CC} = 5.25V			120	mA
Capacitance						
		$\overline{CE}1$ or $\overline{CE}2$ = High, V_{CC} = 5.0V				
C_{IN}	Input	V_{IN} = 2.0V		5		pF
C_{OUT}	Output	V_{OUT} = 2.0V		8		pF

NOTES:
1. Positive current is defined as into the terminal referenced.
2. All voltages with respect to network ground.
3. Typical values are at V_{CC} = 5V, T_{amb} = +25°C.
4. Duration of short circuit should not exceed 1 second.
5. Measured with all inputs grounded and all outputs open.

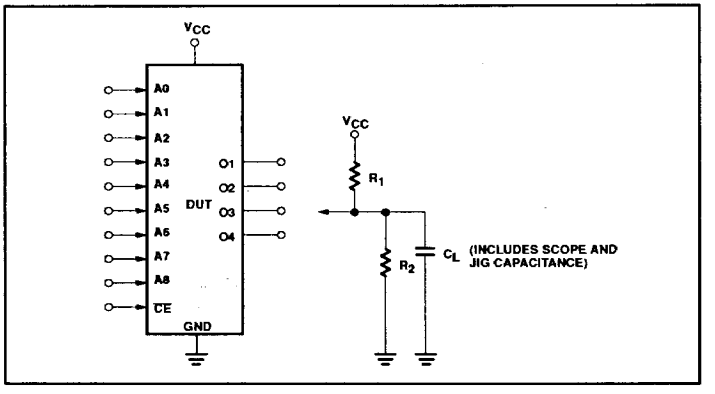
AC ELECTRICAL CHARACTERISTICS

$R_1 = 270\Omega$, $R_2 = 600\Omega$, $C_L = 30pF$, $0°C \leq T_{amb} \leq +75°C$, $4.75V \leq V_{CC} \leq 5.25V$

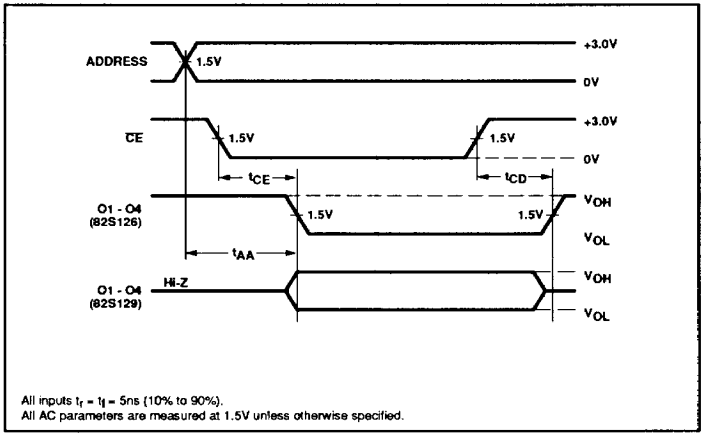
SYMBOL	PARAMETER	TO	FROM	LIMITS			UNIT
				MIN	TYP[1]	MAX	
Access time[2]							
t_{AA}		Output	Address		40	50	ns
t_{CE}		Output	Chip Enable			25	ns
Disable time[3]							
t_{CD}		Output	Chip Disable			25	ns

NOTES:
1. Typical values are at $V_{CC} = 5V$, $T_{amb} = +25°C$.
2. Tested at an address cycle time of 1µs.
3. Measured at a delta of 0.5V from Logic Level with $R_1 = 750\Omega$, $R_2 = 750\Omega$, $C_L = 5pF$.

TEST LOAD CIRCUIT



VOLTAGE WAVEFORMS



All inputs $t_r = t_f = 5ns$ (10% to 90%).
All AC parameters are measured at 1.5V unless otherwise specified.